

**UNIVERSITI TEKNOLOGI MARA**

**SENSITIVITY BEHAVIOR OF  
NANOSTRUCTURED ZINC OXIDE  
BASED GAS SENSOR FABRICATED  
BY IMMERSION METHOD**

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Thesis submitted in fulfillment  
of the requirements for the degree of  
**Master of Science**


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## AUTHOR'S DECLARATION

I declare that the work in this thesis was carried out in accordance with the regulations of Universiti Teknologi MARA. It is original and is the result of my work, unless otherwise indicated or acknowledged as referenced work. This thesis has not been submitted to any other academic institution or non-academic institution for any other degree or qualification.

I, hereby, acknowledge that I have been supplied with the Academic Rules and Regulations for Post Graduate, Universiti Teknologi MARA, regulating the conduct of my study and research.

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## ABSTRACT

This study aimed to fabricate nanostructured zinc oxide (ZnO) based metal-semiconductor-metal (MSM) gas sensor by immersion method. Three stages of method were employed to fabricate nanostructured ZnO based MSM gas sensor which are: (1) preparation of ZnO nano-template by spin-coating method, (2) preparation of nanostructured ZnO on deposited ZnO nano-template layer by immersion method and (3) fabrication of nanostructured ZnO based MSM gas sensor. For preparation of ZnO nano-template by spin-coating method, both effects of multilayer coating (1 to 9 layers) and annealing temperature (350 to 500°C) of ZnO nano-template were determined. The optimised properties of deposited ZnO nano-template was further employed as a seed layer to grow nanostructured ZnO by immersion method. For preparation of nanostructured ZnO on deposited ZnO nano-template layer by immersion method, effect of molarity (0.02 to 0.10 M) and effect of n-type dopant (Sn) concentration (0.2 to 1.0 at.%) on nanostructured ZnO were evaluated. Field emission scanning electron microscope (FESEM), energy dispersive X-ray (EDS), atomic force microscopy (AFM) and X-ray diffraction (XRD) were employed to characterise the structural properties of deposited samples whereby UV-Vis-NIR spectrophotometer was used for the optical properties determination. The electrical properties were measured using current-voltage (I-V) measurement system (Keithley 2400). Next, gold (Au) was deposited on the nanostructured ZnO as an electrode for the fabrication of nanostructured ZnO based MSM gas sensor. The entire samples were characterised to determine their response and recovery time as well as the sensitivity. The sensitivity behavior of the fabricated samples were determined to detect 20 sccm of methane (CH<sub>4</sub>) gas at operating temperature of 150°C. In preparation of ZnO nano-template by spin-coating method, the results revealed that 5 layers demonstrated a high uniformity with no crack and high electrical conductivity ( $1.1 \times 10^{-3}$  S/cm). Additionally, 500°C has emerged as an optimum temperature upon increment of annealing temperatures. During preparation of nanostructured ZnO on deposited ZnO nano-template layer by immersion method, unique nanostructure (flake-like morphologies) was observed upon the study of molarity effect on nanostructured ZnO (0.02-0.10 M). The electrical conductivity was obtained around  $10^{-3}$  S/cm, which is comparable to previous reported studies. The optimum concentration at 0.06 M has exhibited a good uniformity with low roughness and the highest conductivity of  $3.3 \times 10^{-3}$  S/cm. The effect of n-type dopant (Sn) concentration (0.2-1.0 at.%) has been investigated. The width of flakes have slightly decreased from 64.1 to 41.9 nm as the n-type dopant (Sn) concentration increased. Increasing the n-type dopant (Sn) concentration has greatly enhanced the electrical conductivity from  $6.5 \times 10^{-3}$  to  $12.6 \times 10^{-3}$  S/cm. The highest sensitivity was achieved at 23% with utilisation of 1.0 at.%. The response and recovery time of 1.0 at.% were 46 and 64 s, respectively. Through this research work, the optimum preparation parameters were successfully identified for fabrication of nanostructured ZnO based MSM gas sensor. This work provides an opportunity to explore potential material for the development of gas sensor.

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